

MBR1535CT - MBR1560CT

Features

- · Low power loss, high efficiency.
- · High surge capacity.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- · Metal silicon junction, majority carrier conduction.
- High current capacity, low forward voltage drop.
- Guarding for over voltage protection.



Schottky Rectifiers

Absolute Maximum Ratings*

T_A = 25 °C unless otherwise noted

TO-220AB

Symbol	Parameter	Value				Units
		1535	1545	1550	1560	
V_{RRM}	Maximum Repetitive Reverse Voltage	35	45	50	60	V
I _{F(AV)}	Average Rectified Forward Current .375 " lead length @ $T_A = 105$ °C	15		А		
I _{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	150			Α	
T _{stg}	Storage Temperature Range -65 to +175		+175		°C	
T _J	Operating Junction Temperature	-65 to +150				°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	41.7	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	60	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	3.0	°C/W

Electrical Characteristics T_A = 25 °C unless otherwise noted

Symbol	Parameter	Device				Units
		1535	1545	1550	1560	
V _F	Forward Voltage $I_{F=}$ 7.5 A, T_{C} = 25°C $I_{F=}$ 7.5 A, T_{C} = 125°C $I_{F=}$ 15 A, T_{C} = 25°C $I_{F=}$ 15 A, T_{C} = 125°C	- 0.57 0.84 0.72		0.75 0.65 - -		V V V
I _R	Reverse Current @ rated V_R $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$	0.1 1.0 15 50		mA mA		
I _{RRM}	Peak Repetitive Reverse Surge Current 1.0 2.0 us Pulse Width, f = 1.0 KHz		0	0	.5	Α

Schottky Rectifier

(continued)

Typical Characteristics

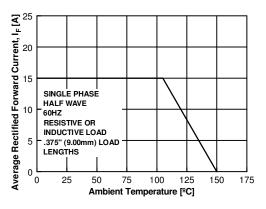


Figure 1. Forward Current Derating Curve

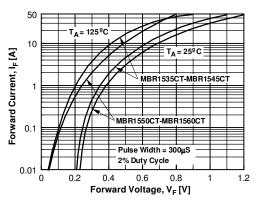


Figure 3. Forward Voltage Characteristics

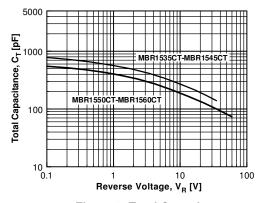


Figure 5. Total Capacitance

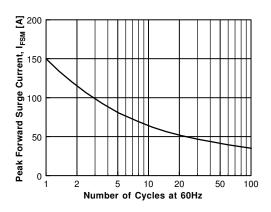


Figure 2. Non-Repetitive Surge Current

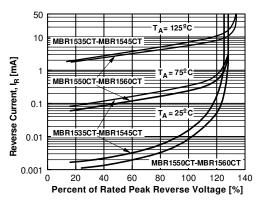


Figure 4. Reverse Current vs Reverse Voltage

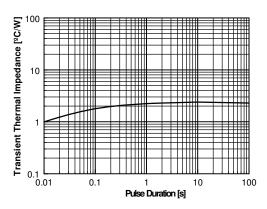


Figure 6. Thermal Impedance Characteristics

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